

Hong Zhou

List of Publications by Year in descending order

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59
papers

3,273
citations

159358

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143772

57
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all docs

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docs citations

59
times ranked

5143
citing authors

#	ARTICLE	IF	CITATIONS
1	Growth of Alloy MoS ₂ X ₂ Se ₂ Nanosheets with Fully Tunable Chemical Compositions and Optical Properties. <i>Journal of the American Chemical Society</i> , 2014, 136, 3756-3759.	6.6	444
2	Directional Growth of Ultralong CsPbBr ₃ Perovskite Nanowires for High-Performance Photodetectors. <i>Journal of the American Chemical Society</i> , 2017, 139, 15592-15595.	6.6	260
3	Vapor Growth and Tunable Lasing of Band Gap Engineered Cesium Lead Halide Perovskite Micro/Nanorods with Triangular Cross Section. <i>ACS Nano</i> , 2017, 11, 1189-1195.	7.3	245
4	Lateral Growth of Composition Graded Atomic Layer MoS ₂ X ₂ Se ₂ Nanosheets. <i>Journal of the American Chemical Society</i> , 2015, 137, 5284-5287.	6.6	191
5	Room-Temperature Near-Infrared Photodetectors Based on Single Heterojunction Nanowires. <i>Nano Letters</i> , 2014, 14, 694-698.	4.5	134
6	Perovskite-Erbium Silicate Nanosheet Hybrid Waveguide Photodetectors at the Near-Infrared Telecommunication Band. <i>Advanced Materials</i> , 2017, 29, 1604431.	11.1	132
7	Broken Symmetry Induced Strong Nonlinear Optical Effects in Spiral WS ₂ Nanosheets. <i>ACS Nano</i> , 2017, 11, 4892-4898.	7.3	123
8	High-Performance Flexible Photodetectors based on High-Quality Perovskite Thin Films by a Vapor Solution Method. <i>Advanced Materials</i> , 2017, 29, 1703256.	11.1	121
9	Direct Vapor Growth of Perovskite CsPbBr ₃ Nanoplate Electroluminescence Devices. <i>ACS Nano</i> , 2017, 11, 9869-9876.	7.3	117
10	Cesium lead halide perovskite triangular nanorods as high-gain medium and effective cavities for multiphoton-pumped lasing. <i>Nano Research</i> , 2017, 10, 3385-3395.	5.8	113
11	Single-Crystalline InGaAs Nanowires for Room-Temperature High-Performance Near-Infrared Photodetectors. <i>Nano-Micro Letters</i> , 2016, 8, 29-35.	14.4	101
12	Composition-Modulated Two-Dimensional Semiconductor Lateral Heterostructures via Layer-Selected Atomic Substitution. <i>ACS Nano</i> , 2017, 11, 961-967.	7.3	99
13	Semiconductor Alloy Nanoribbon Lateral Heterostructures for High-Performance Photodetectors. <i>Advanced Materials</i> , 2014, 26, 2844-2849.	11.1	70
14	Low-Threshold Nanowire Laser Based on Composition-Symmetric Semiconductor Nanowires. <i>Nano Letters</i> , 2013, 13, 1251-1256.	4.5	67
15	Band-Selective Infrared Photodetectors with Complete Composition Range InAs _x P _{1-x} Alloy Nanowires. <i>Advanced Materials</i> , 2014, 26, 7444-7449.	11.1	67
16	Vapor growth and interfacial carrier dynamics of high-quality CdS-CdS _{1-x} Se _x -CdS axial nanowire heterostructures. <i>Nano Energy</i> , 2017, 32, 28-35.	8.2	62
17	Strong thickness-dependent quantum confinement in all-inorganic perovskite Cs ₂ PbI ₄ with a Ruddlesden-Popper structure. <i>Journal of Materials Chemistry C</i> , 2019, 7, 7433-7441.	2.7	62
18	Oriented tuning the photovoltaic properties of RbGeX_3 by strain-induced electron effective mass mutation. <i>Journal Physics D: Applied Physics</i> , 2017, 50, 465101.	1.3	50

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19	Significantly Enhanced Red Photoluminescence Properties of Nanocomposite Films Composed of a Ferroelectric Bi _{3.6} Eu _{0.4} Ti ₃ O ₁₂ Matrix and Highly c-Axis-Oriented ZnO Nanorods on Si Substrates Prepared by a Hybrid Chemical Solution Method. <i>Journal of the American Chemical Society</i> , 2010, 132, 1790-1791.	6.6	49
20	Nanolaser arrays based on individual waved CdS nanoribbons. <i>Laser and Photonics Reviews</i> , 2016, 10, 458-464.	4.4	49
21	Strong upconversion luminescence properties of Yb ³⁺ and Er ³⁺ codoped Bi ₄ Ti ₃ O ₁₂ ferroelectric thin films. <i>Journal of Applied Physics</i> , 2009, 106, 126104.	1.1	46
22	Strong red emission in lead-free ferroelectric Pr ³⁺ -doped Na _{0.5} Bi _{0.5} TiO ₃ thin films without the need of charge compensation. <i>Journal of Applied Physics</i> , 2011, 110, 034102.	1.1	46
23	Up-conversion luminescence and optical temperature-sensing properties of Er ³⁺ -doped perovskite Na _{0.5} Bi _{0.5} TiO ₃ nanocrystals. <i>Journal of Physics and Chemistry of Solids</i> , 2016, 98, 28-31.	1.9	44
24	High Gain Submicrometer Optical Amplifier at Near-Infrared Communication Band. <i>Physical Review Letters</i> , 2015, 115, 027403.	2.9	43
25	Nonlinear photoluminescence in monolayer WS ₂ : parabolic emission and excitation fluence-dependent recombination dynamics. <i>Nanoscale</i> , 2017, 9, 7235-7241.	2.8	41
26	First-principles investigations of electronic and optical properties in the MoS ₂ /CsPbBr ₃ heterostructure. <i>Journal of Physics and Chemistry of Solids</i> , 2019, 135, 109060.	1.9	39
27	Room-temperature high-performance CsPbBr ₃ perovskite tetrahedral microlasers. <i>Nanoscale</i> , 2019, 11, 2393-2400.	2.8	38
28	Dual Enhancement of Photoluminescence and Ferroelectric Polarization in Pr ³⁺ /La ³⁺ -Codoped Bismuth Titanate Thin Films. <i>Journal of the American Ceramic Society</i> , 2010, 93, 2109-2112.	1.9	37
29	Improved Electrical Properties and Strong Red Emission of K ⁺ -Doped Bi ³⁺ -Doped Lead-Free Ferroelectric Thin Films. <i>Journal of the American Ceramic Society</i> , 2012, 95, 483-486.	1.9	35
30	Bright up-conversion photoluminescence of Bi ³⁺ /Er ³⁺ -Ti ₃ O ₁₂ ferroelectric thin films. <i>Journal of Applied Physics</i> , 2011, 109, 043106-043106-5.	1.1	33
31	Lateral composition-graded semiconductor nanoribbons for multi-color nanolasers. <i>Nano Research</i> , 2016, 9, 933-941.	5.8	33
32	Combination of Strong Blue Up-Conversion Photoluminescence and Greatly Enhanced Ferroelectric Polarization in Tm ³⁺ -Yb ³⁺ -W ⁶⁺ -Doped Bi ₄ Ti ₃ O ₁₂ Thin Films. <i>Journal of the Electrochemical Society</i> , 2011, 158, G128.	1.3	26
33	Synthesis and Diameter-dependent Thermal Conductivity of InAs Nanowires. <i>Nano-Micro Letters</i> , 2014, 6, 301-306.	14.4	25
34	Epitaxial growth of CsPbBr ₃ -PbS vertical and lateral heterostructures for visible to infrared broadband photodetection. <i>Nano Research</i> , 2021, 14, 3879-3885.	5.8	25
35	Surface plasmon resonance enhanced band-edge emission of CdS@SiO ₂ core-shell nanowires with gold nanoparticles attached. <i>Journal of Materials Chemistry C</i> , 2013, 1, 566-571.	2.7	23
36	Effective shape-controlled synthesis of gallium selenide nanosheets by vapor phase deposition. <i>Nano Research</i> , 2020, 13, 557-563.	5.8	22

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37	Colossal resistive switching behavior and its physical mechanism of Pt/p-NiO/n-Mg _{0.6} Zn _{0.4} O/Pt thin films. <i>Applied Physics A: Materials Science and Processing</i> , 2011, 104, 477-481.	1.1	16
38	Microphotoluminescence of individual ZnSe nanoribbons. <i>Materials Letters</i> , 2014, 129, 118-121.	1.3	15
39	Bandgap broadly tunable GaZnSeAs alloy nanowires. <i>Physical Chemistry Chemical Physics</i> , 2013, 15, 2912.	1.3	13
40	Self-catalytic VLS growth one dimensional layered GaSe nanobelts for high performance photodetectors. <i>Journal of Physics and Chemistry of Solids</i> , 2018, 118, 186-191.	1.9	13
41	Growth and Electrical Properties of 25%Bi(Ni _{1/2} Ti _{1/2})O ₃ -75%PbTiO ₃ Thin Films on Pt/TiO ₂ /SiO ₂ /Si Substrates Using Pulsed Laser Deposition Method. <i>Journal of the American Ceramic Society</i> , 2011, 94, 1675-1678.	1.9	10
42	Down-conversion luminescence and its temperature-sensing properties from Er ³⁺ -doped sodium bismuth titanate ferroelectric thin films. <i>Applied Physics A: Materials Science and Processing</i> , 2015, 121, 773-777.	1.1	10
43	Synthesis and optical properties of InP quantum dot/nanowire heterostructures. <i>Physica Status Solidi (A) Applications and Materials Science</i> , 2013, 210, 1898-1902.	0.8	9
44	Er ³⁺ -doped Na _{0.5} Bi _{0.5} TiO ₃ ferroelectric thin films with enhanced electrical properties and strong green up-conversion luminescence. <i>Applied Physics A: Materials Science and Processing</i> , 2015, 119, 937-940.	1.1	9
45	Large photoluminescence redshift of ZnTe nanostructures: The effect of twin structures. <i>Chemical Physics Letters</i> , 2013, 576, 26-30.	1.2	8
46	Complete composition tunability of Cd _{1-x} Zn _x Te alloy nanostructures along a single substrate. <i>Materials Letters</i> , 2013, 105, 90-94.	1.3	8
47	Dielectric properties and bright red emission of Y ³⁺ /Eu ³⁺ -codoped ZrO ₂ thin films prepared by chemical solution deposition. <i>Ceramics International</i> , 2013, 39, 1335-1340.	2.3	7
48	Structural, Dielectric, and Ferroelectric Properties of BiAlO ₃ -PbTiO ₃ Solid Solution Thin Films on Indium Tin Oxide-Coated Glass Substrates. <i>Journal of the American Ceramic Society</i> , 2010, 93, 925-927.	1.9	6
49	Optical characteristics of Bi _{4-x} Eu _x Ti ₃ O ₁₂ ferroelectric thin films on fused silica substrates. <i>Journal of Electroceramics</i> , 2012, 29, 37-41.	0.8	6
50	Second harmonic generation and waveguide properties in perovskite Na _{0.5} Bi _{0.5} TiO ₃ nanowires. <i>Optics Letters</i> , 2016, 41, 3803.	1.7	6
51	Improved photoluminescence and ferroelectric properties of (Bi _{3.6} Eu _{0.4})Ti ₃ O ₁₂ thin films via Li-doping. <i>IEEE Transactions on Ultrasonics, Ferroelectrics, and Frequency Control</i> , 2010, 57, 2134-2137.	1.7	5
52	Improved Red Photoluminescence and Ferroelectricity in Layered Composite (Bi,Eu) ₄ Ti ₃ O ₁₂ /ZnO Thin Films. <i>Applied Physics Express</i> , 2011, 4, 032103.	1.1	5
53	Preparation and Photoluminescence of Praseodymium-Doped Bismuth Titanate Ferroelectric Thin Films. <i>Ferroelectrics</i> , 2010, 406, 108-113.	0.3	4
54	Silicon-erbium ytterbium silicate nanowire waveguides with optimized optical gain. <i>Frontiers of Physics</i> , 2017, 12, 1.	2.4	4

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55	Color-tunable photoluminescence in Bi _{3.6} Eu _{0.4} Ti ₃ O ₁₂ /ZnO nanorods composite films. <i>Ceramics International</i> , 2013, 39, S507-S511.	2.3	2
56	Wang <i>et al.</i> Reply. <i>Physical Review Letters</i> , 2016, 117, 219702.	2.9	2
57	Photoluminescence and Raman spectroscopy characterization of highly c-axis oriented Mg _x Zn _{1-x} O thin films on Pt-coated silicon substrates. <i>Journal of Electroceramics</i> , 2011, 27, 162-168.	0.8	1
58	Comparative investigation of unipolar resistance switching effect of Pt/Mg _{0.6} Zn _{0.4} O/Pt devices with different electrode patterns for nonvolatile memory application. <i>Applied Physics A: Materials Science and Processing</i> , 2012, 108, 503-508.	1.1	1
59	Scalable Fabrication of Bi ₂ O ₂ Se Polycrystalline Thin Film for Near-infrared Optoelectronic Devices Applications. <i>Chinese Physics B</i> , 0, , .	0.7	1